

# Infiltration of CNT-M Microstructures using CVD and ALD

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### Outline

Purpose of Deposition Techniques

Overview of CNT-M

Theory of Deposition

Chemical Vapor Deposition (CVD)

Atomic Layer Deposition (ALD)

Conversion of CVD system to ALD

Initial Results

Initial Characterization with SEM, TEM, and XEDS

### Purpose

### Create mechanical and electrical components on a micro scale - NEMS/MEMS



### Why does this matter?

- High sensitivity inertial sensors
- X-ray collimator







(1)

<u>http://www.ducksters.com/games/</u> wii-sports-bowling.php

### **Traditional Fabrication Method**

### Etching-

Chemically or mechanically removing selective parts of a solid metal



(3)

### Limitations of Chemical Etching

Limited selection of materials -Tungsten, Gold, Silicon, Aluminum

Poor aspect ratio (height to width)

\*(~5:1) aspect ratio due to gas transportation limits



### **New Method for NEMS/MEMS**

- Carbon Nanotube Templated Micro-fabrication (CNT-M)
- Easily Controlled
- High Aspect Ratio (200:1)



features >500 microns tall by 2-3 microns across

Electrically conductive



## Chemical Vapor Deposition (CVD)

- When used to infiltrate a CNT, called Chemical Vapor Infiltration (CVI)
- Flow reactants into chamber constantly, usually at high temperature
- Heat the solid precursor so it will volatilize
- Flow an inert gas to carry the precursor to the sample
- Problems
  - Uneven Infiltration
  - Capping



Before infiltration

# After infiltration

Forest - 1% Carbon

Carbon Nanotube Forest Infiltrated with Mo(CO)<sub>6</sub> by Richard Hansen









### Atomic Layer Deposition (ALD)

Propose to try with Tungsten in nanotube forests, so Atomic Layer Infiltration (AFI)

Self-limiting layer by layer

Hope to achieve:

uniform material properties

eliminate crusts

### Tungsten ALD with WF<sub>6</sub>

Gaseous form of WF<sub>6</sub> self-limits deposition

Flow H<sub>2</sub>, monatomic Hydrogen from Plasma, or Silane (SiH<sub>4</sub>)

H reduces WF<sub>6</sub> leaving a layer of W

HF gas molecules created



### **Converting the System**

Modified from CVD

Hooked in gas lines for WF<sub>6</sub>

Seal cabinet, install cabinet exhaust system, and insert sensors and filters for HF.

♣ Automate Labview<sup>TM</sup> program to cycle valves for ALD







### **Initial Results**





### Plasma - RF generated





### Latest Deposition - Pseudo ALD

- Constant H •(40 sccm) from a Hydrogen Plasma
- 5 seconds of WF<sub>6</sub> (0.0142 I at 5 psi, about 2.0 x 10<sup>-4</sup> mole)
- 120 cycles
- 235 degrees C sample temperature
- Ozone treated 1 of the samples for 20 min, for better nucleation

### Ozone treatment vs No Ozone treatment







Top of Sample - Break in Lower Left

Image of Fresh Surface from Break





- scattered peaks have a lattice spacing too large for BCC tungsten
- \* may be an A15 compound, something like Beta-Tungsten

### **Future Plans**

- Optimize procedure (Intervals, flow rates, etc.)
  - Silane vs. Hydrogen
  - Ozone treatment vs. No Ozone treatment vs. In Situ Ozone treatment
  - Annealing
- Characterization by SEM & TEM cross sectioning, Also X-ray characterization at ALS, FIB
  - Capping
  - Grain size uniformity
- Electrical conductivity
- Mechanical Properties

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